

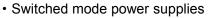
isc N-Channel MOSFET Transistor

IXFA72N20X3

• FEATURES

- Static drain-source on-resistance:
 R_{DS}(on) ≤ 20mΩ@V_{GS}=10V
- Fully characterized avalanche voltage and current
- 100% Avalanche Tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATION



• DC-DC converters

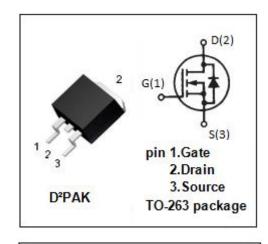


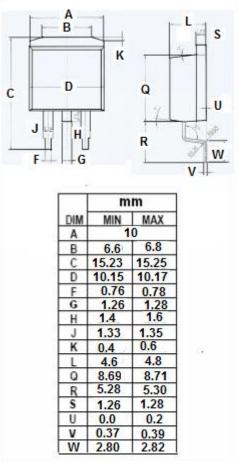
• ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	200	V	
V _{GS}	Gate-Source Voltage	±20	V	
ID	Drain Current-Continuous 72		А	
I _{DM}	Drain Current-Single Pulsed 130		А	
P_D	Total Dissipation @T _C =25℃ 320		W	
Tj	Operating Junction Temperature -55~150		$^{\circ}$ C	
T _{stg}	Storage Temperature	-55~150	${\mathbb C}$	

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th(j-c)}	Junction-to-case thermal resistance	0.39	°C/W





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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0V; ID = 250 μ A	200		V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; ID = 1.5mA	2.5	4.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D = 36A		20	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} =0V		±100	nA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = V _{DSS} ; V _{GS} = 0V		5	- μΑ
		V _{DS} = V _{DSS} ; V _{GS} = 0V;T _J = 125°C		250	
Vsp	Diode forward voltage	I _F = 72A; V _{GS} = 0V		1.4	V



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